

10/568227

1AP20 Rec'd PCT/PTO 14 FEB 2006

Customer No. 22,852

Attorney Docket No. 02814.0087

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:

Vivian ALBERTS

Application No.: **Not Yet Assigned**

Filed: **February 14, 2006**

National Stage of International Application No.

PCT/IB2004/051458 under 35 U.S.C. 371, for

METHOD FOR THE PREPARATION OF

GROUP IB-III A-VIA QUATERNARY OR

HIGHER ALLOY SEMICONDUCTOR FILMS

Group Art Unit: **Not Yet Assigned**

Examiner: **Not Yet Assigned**

MAIL STOP PCT

Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

Sir:

INFORMATION DISCLOSURE STATEMENT UNDER 37 C.F.R. § 1.97(b)

Pursuant to 37 C.F.R. §§1.56 and 1.97(b), applicant brings to the Examiner's attention the documents listed on attached Form PTO/SB/08 and cited in the international search report. With exception of the U.S. patent, copies of the listed documents are attached. Applicant respectfully requests that the Examiner consider the documents listed on attached Form PTO/SB/08 and indicate that they were considered by making an appropriate notation on this form. This Information Disclosure Statement is being filed with the above-referenced application.

Also enclosed is an English-language international search report from the European Patent Office in the PCT international application, from which this national phase U.S. application is derived.

This submission does not represent that a search has been made or that no better art exists and does not constitute an admission that each or all of the listed documents are material or constitute "prior art." If the Examiner applies any of the

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1AP20 REGISTRATION 14 FEB 2006

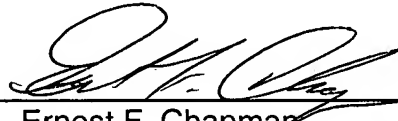
documents as prior art against any claim in the application and applicant determines that the cited documents do not constitute "prior art" under United States law, applicant reserves the right to present to the Office the relevant facts and law regarding the appropriate status of such documents. Applicant further reserves the right to take appropriate action to establish the patentability of the disclosed invention over the listed documents, should one or more of the documents be applied against the claims of the present application.

If there is any fee due in connection with the filing of this Statement, please charge the fee to our Deposit Account No. 06-0916.

Respectfully submitted,

FINNEGAN, HENDERSON, FARABOW,
GARRETT & DUNNER, L.L.P.

Dated: February 14, 2006

By: 
Ernest F. Chapman
Reg. No. 25,961

Enclosures
EFC/FPD/sci

IDS Form PTO/SB/08: Substitute for form 1449A/PTO				Complete if Known	
				Application Number	Not Yet Assigned
INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use as many sheets as necessary)				Filing Date	February 14, 2006
				First Named Inventor	Vivian ALBERTS
				Art Unit	Not Yet Assigned
				Examiner Name	Not Yet Assigned
				Attorney Docket Number	02814.0087
Sheet	1	of	1		

U.S. PATENTS AND PUBLISHED U.S. PATENT APPLICATIONS					
Examiner Initials	Cite No. ¹	Document Number	Issue or Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number-Kind Code ² (if known)			
		US-5,436,204	07-25-1995	ALBIN et al.	

Note: Copies of the U.S. Patent Documents are not Required in IDS filed after October 21, 2004

FOREIGN PATENT DOCUMENTS						
Examiner Initials	Cite No. ¹	Foreign Patent Document	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	Translation ⁶
		Country Code ³ Number ⁴ Kind Code ⁵ (if known)				

NON PATENT LITERATURE DOCUMENTS			
Examiner Initials	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	Translation ⁶
		NAGOYA, Y. et al., "Role of Incorporated Sulfur Into the Surface of Cu(InGa)Se ₂ Thin-Film Absorber," Solar Energy Materials & Solar Cells, Vol. 67, pp. 247-253, (2001).	
		KUSHIYA, K. et al., "Formation Chemistry of Polycrystalline Cu(InGa)Se ₂ Thin-Film Absorbers Prepared by Selenization of Cu-Ga/In Stacked Precursor Layers with H ₂ Se Gas," Mat. Res. Soc. Symp. Proc., Vol. 426, pp. 177-182, (1996).	
		KUSHIYA, K. et al., "Development of Cu(InGa)Se ₂ Thin-Film Solar Cells With Zn-Compound Buffer," 13 th European Photovoltaic Solar Energy Conference, Nice, France, Vol. 2 of 2, Conf. 13, pp. 2016-2019, (October 1995).	
		KUSHIYA, K. et al., "The Role of Cu(InGa)(SeS) ₂ Surface Layer on a Graded Band-Gap Cu(InGa)Se ₂ Thin-Film Solar Cell Prepared by Two-Stage Method," 25 th IEEE Photovoltaic Specialists Conference, pp. 989-992, (May 1996).	

Examiner Signature		Date Considered	
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EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.